REZULTETUTETO SULLAN 2005

SHEET 1 OF 1

Form PTO 1449 U.S. DEPARTMENT OF COMMERCE (Modified) PATENT AND TRADEMARK OFFICE			ATTY DOCKET NO. 291682US2RD PCT		New U.S. PCT Application Based on PCTJP06/305070				
			APPLICANT Based on PCTJP06/305						
LIST OF REFERENCES CITED BY APPLICANT				Ryoichi OHARA, et al.					
				FILING DATE		GROUP			
			Herewith		GROUP				
				· · · · · · · · · · · · · · · · · · ·					
		T		U.S. PATENT DOCUMENTS	· · · · · · · · · · · · · · · · · · ·		T		
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE		
/DR/	AA	2005-142888	06/30/05	EBUCHI et al.					
/DR/	AB	6 384 697	05/07/02	RUBY		8			
	AC			,					
	AD						_		
	AE								
	AF						_		
	AG		1						
	AH								
	AI		1	,, ,,,,					
	AJ								
	AK								
	AL								
	AM	,			- 				
	AN					<u> </u>			
	AN					L			
			FO	REIGN PATENT DOCUMENTS					
		DOCUMENT NUMBER	DATE	COUNTRY		TRANSLATION YES NO			
	AO								
	AP								
	AQ								
	AR					-			
	AS								
	AT								
	AU								
	AV								
		OTHER R	EFERENCES (Including Author, Title, Date, Pertine	nt Pages, e	tc.)			
/DR/	AW	LAKIN, K. M. et al., " 1.0-GHz thin-film bulk acoustic wave resonators on GaAs", Appl. Phys. Letter, Vol. 43, No. 8, Pages 750 - 751, 1983.							
	AX	-							
	AY								
	AZ				Addi	tional Refe	erences sheet(s) attached		
Examiner	/De	erek Rosenau/ Date Considered 06/02/2008					06/02/2008		
				citation is in conformance with MPEP 6 with next communication to applicant.	609; Draw lir	ne through	citation if not in		

New U.S. PCT Application Based on PCT/JP06/305070 Ryoichi OHARA, et al. Docket No. 291682 US

STATEMENT OF RELEVANCY

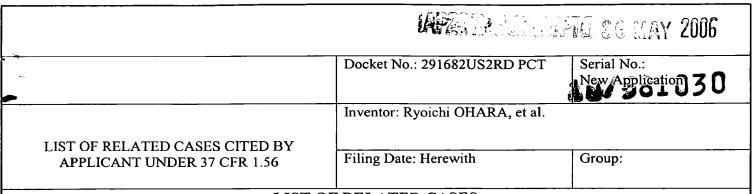
- 1) References have been cited in the International Search Report. A copy of these references is being submitted herewith.
- 2) References have been cited in the corresponding Search Report. A copy of these references is being submitted herewith.
- 3) References AB & AW are discussed in the specification. A copy of these references is being submitted herewith.
- 4) References are additional prior art known to Applicant. A copy of these references is being submitted herewith.

AB: 6,384,697

Technologies of FBAR using a bottom electrode which has edges extending beyond each boundary of cavity are disclosed.

AW: LAKIN, K. M. et al., "1.0-GHz thin-film bulk acoustic wave resonators on GaAs", Appl. Phys. Letter, Vol. 43, No. 8, Pages 750 - 751, 1983.

Technologies of FBAR using a bottom electrode which has edges extending beyond each boundary of cavity are disclosed.



LIST OF RELATED CASES

Examine <u>Initial</u>	Docket No.	Serial or <u>Patent</u> <u>Number</u>	Filing or Issue Date	Patent App. <u>Publication</u> <u>No.</u>	Inventor or Applicant
/DR/	256032US2	10/890,989	07/15/04	2005-142888	EBUCHI, et al.
/DR/	287666US2RD	11/376,266	03/16/06		YANASE, et al.

Examiner

/Derek Rosenau/

Date Considered

06/02/2008